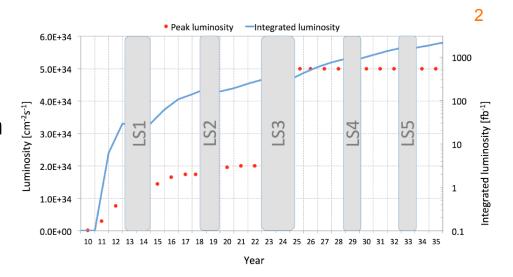


# Measuring Single Event Upsets in the ATLAS Inner Tracker

Noah Lupu-Gladstein April 9th, 2015

# High Luminosity (HL) LHC and ATLAS

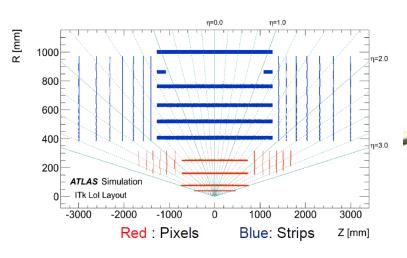
- "A highly performant tracker underpins the entire ATLAS physics program"<sup>1</sup>
- "The much harsher radiation and occupancy conditions of the HL-LHC necessitates a complete replacement of the present ID" (Inner Detector)<sup>1</sup>

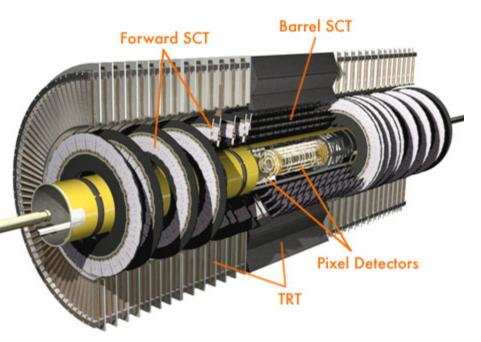


- 1. ATLAS Letter of Intent Phase-II Upgrade
- 2. LHC Commissioning. http://lhc-commissioning.web.cern.ch/lhc-commissioning/schedule/LHC-schedule-update.pdf

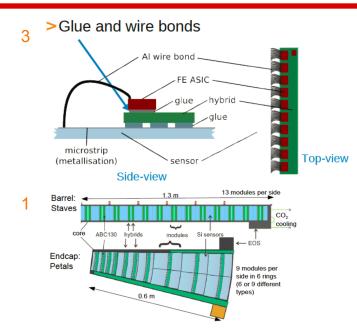
## **The ATLAS Inner Detector**

- SCT = SemiConducting Tracker
- Use Silicon to detect charged particles





# **Strip Detector Design**





3. FRAIS-Workshop "From Silicon Sensor to Full Detector System". Richard Teuscher. <u>https://indico.cern.ch/event/382226/</u> contribution/1/material/slides/0.pdf

# The ABC130

Higher luminosity means:

- More pileup
- More radiation damage



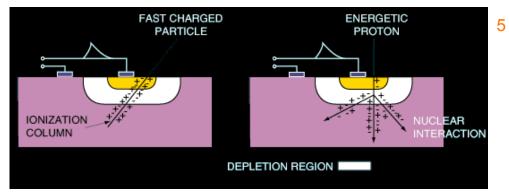
The ABC130 significantly differs from the ABCn and predecessors. 4 The main changes are listed below:

- 130nm CMOS technology
- 1.3V external power supply
- Three Trigger types, L0, R3 and L1 control the data flow.
- Fixed Length data structure with multiple data types.
- Xon / Xoff flow control between chips.
- Readout clock up to 160Mbits/sec.
- Readout mode compatible with an external Hybrid Controller Chip, HCC
- Bonding pads arrangement, chip size fitting to the hybrid prototype
- SEU errors handling
- I/O and register scan through JTAG
- Fast cluster finder logic

4. ABC130 Specifications. https://indico.cern.ch/event/227566/material/0/0.pdf

# Single Event Effects (SEE)

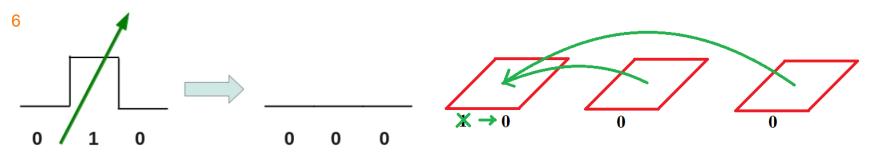
- High-energy charged particle interferes with device operation
- Single Event Latchup (SEL)
  - Single Event Burnout (SEB)
    - Single Event Upset (SEU)



5. Single Event Effects. http://holbert.faculty.asu.edu/eee560/see.html

## The ABC130 and SEUs

- SEUs are "soft" errors
- Harder to detect during operation
- ABC130 uses register triplication



 DAQ for SEU Studies on ABC130 chips. Richard Teuscher, Kyle Cormier, Noah Lupu-Gladstein, Luigi Vigani, et al. https://indico.cern. ch/event/361445/session/18/contribution/32/material/slides/0.pdf

## **Experimental Goals**

Report an approximate measurement of SEU cross section and validate triplication correction Dependent Variable:

• SEU cross section

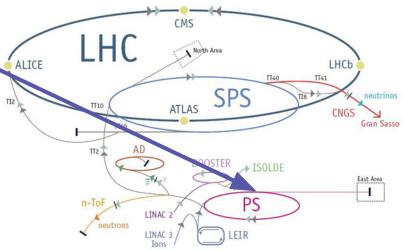
Independent Variables:

- Fluence
- Current consumption
- Other Diagnostics

#### **Test Beam**

Cern High energy AcceleRator Mixed field facility (CHARM):

- 24 GeV/c protons
- One spill every ~300ms
- 2 x 10<sup>9</sup> protons/cm<sup>2</sup>/spill
- $O(10^{14})$  per cm<sup>2</sup> a week<sup>6</sup>



#### Software

- Write and read registers continuously
- Inject "physics" data
- Record Diagnostics (eg: *temp, I, V*)
- Catch SEU Flags
- Analyze Data
- User-friendly
- Integrate with existing software

